

MOS FIELD EFFECT TRANSISTOR

μ PA573T

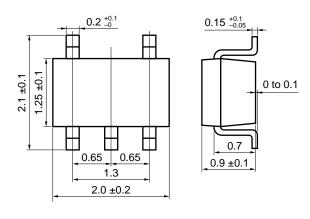
P-CHANNEL MOS FET (5-PIN 2 CIRCUITS) FOR SWITCHING

The μ PA573T is a super-mini-mold device provided with two MOS FET circuits. It achieves high-density mounting and saves mounting costs.

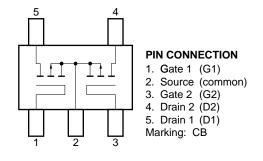
FEATURES

- Two source common MOS FET circuits in package the same size as SC-70
- · Directly driven by ICs having a 3 V power supply
- · Automatic mounting supported

PACKAGE DIMENSIONS (in millimeters)



EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

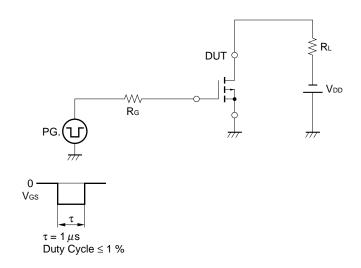
PARAMETER	SYMBOL	TEST CONDITIONS	RATINGS	UNIT
Drain to Source Voltage	VDSS	Ves = 0	-30	V
Gate to Source Voltage	Vgss	V _{DS} = 0	∓7	V
Drain Current (DC)	I _{D(DC)}		∓100	mA
Drain Current (pulse)	ID(pulse)	PW ≤ 10 ms, Duty Cycle ≤ 50 %	∓200	mA
Total Power Dissipation	Рт		200 (Total)	mW
Channel Temperature	Tch		150	°C
Operating Temperature	Topt		-55 to +80	°C
Storage Temperature	T _{stg}		-55 to +150	°C

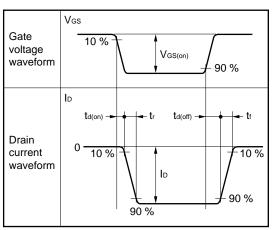


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-off Current	Ipss	$V_{DS} = -30 \text{ V, } V_{GS} = 0$			-1.0	μΑ
Gate Leakage Current	Igss	V _G S = ∓5 V, V _D S = 0			∓3.0	μΑ
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = -3 \text{ V}, \text{ ID} = -10 \mu \text{A}$	-1.6	-1.9	-2.3	V
Forward Transfer Admittance	y _{fs}	$V_{DS} = -3 \text{ V}, I_{D} = -10 \text{ mA}$	20	30		S
Drain to Source On-State Resistance	RDS(on)1	$V_{GS} = -2.5 \text{ V}, \text{ ID} = -1 \text{ mA}$		55	100	Ω
Drain to Source On-State Resistance	RDS(on)2	$V_{GS} = -4.0 \text{ V}, \text{ ID} = -10 \text{ mA}$		20	25	Ω
Input Capacitance	Ciss	V _{DS} = -5.0 V, V _{GS} = 0, f = 1 MHz		16		pF
Output Capacitance	Coss			13		pF
Reverse Transfer Capacitance	Crss			2		pF
Turn-On Delay Time	td(on)	$V_{DD} = -5 \text{ V}, I_{D} = -10 \text{ mA}, V_{GS(on)} = -5 \text{ V},$		10		ns
Rise Time	tr	$R_G = 10 \ \Omega, \ R_L = 500 \ \Omega$		40		ns
Turn-Off Delay Time	td(off)			130		ns
Fall Time	t f			80		ns

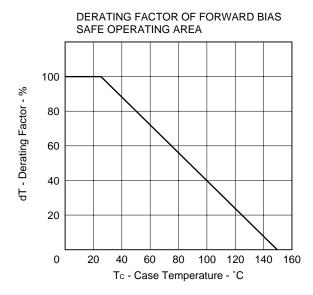
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

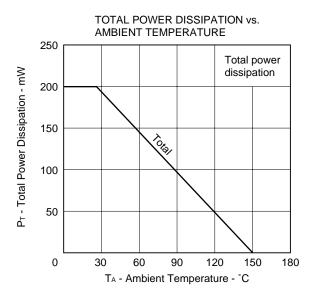


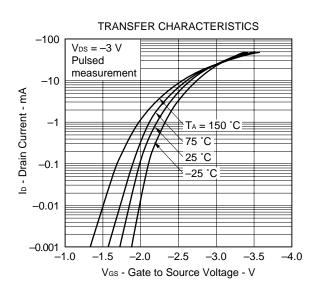


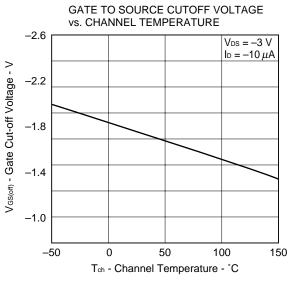


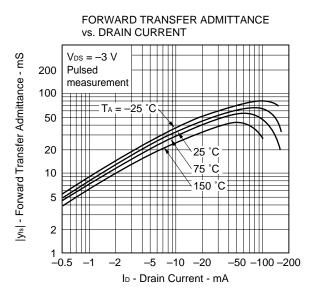
TYPICAL CHARACTERISTICS (TA = 25 °C)

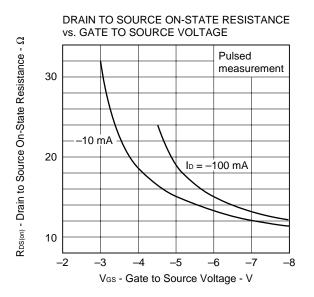




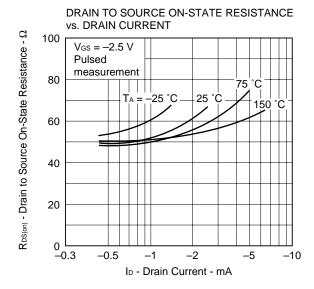


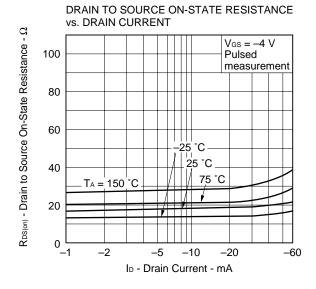


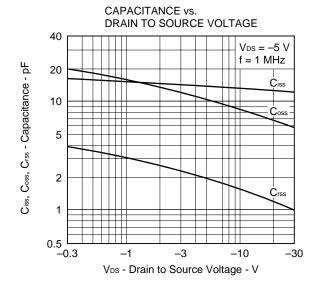


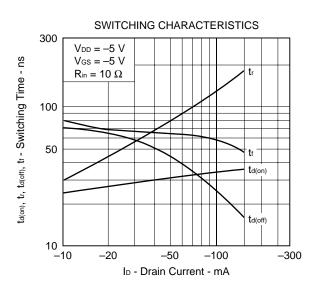


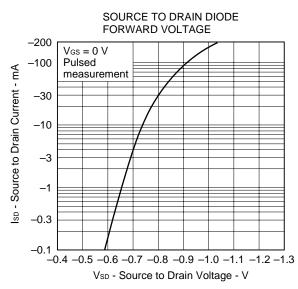


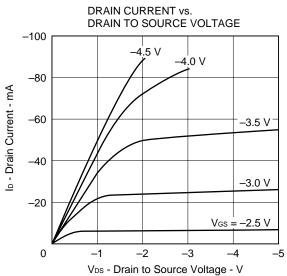














REFERENCE

Document Name	Document No.		
NEC semiconductor device reliability/quality control system	TEI-1202		
Quality grade on NEC semiconductor devices	IEI-1209		
Semiconductor device mounting technology manual	C10535E		
Guide to quality assurance for semiconductor devices	MEI-1202		
Semiconductor selection guide	X10679E		

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Anti-radioactive design is not implemented in this product.

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